

**FEATURES**

- \* 4.0 INCH ( 101.6 mm) DIGIT HEIGHT.
- \* CONTINUOUS UNIFORM SEGMENTS.
- \* LOW POWER REQUIREMENT.
- \* EXCELLENT CHARACTERS APPEARANCE.
- \* HIGH BRIGHTNESS & HIGH CONTRAST.
- \* WIDE VIEWING ANGLE.
- \* SOLID STATE RELIABILITY.
- \* CATEGORIZED FOR LUMINOUS INTENSITY.

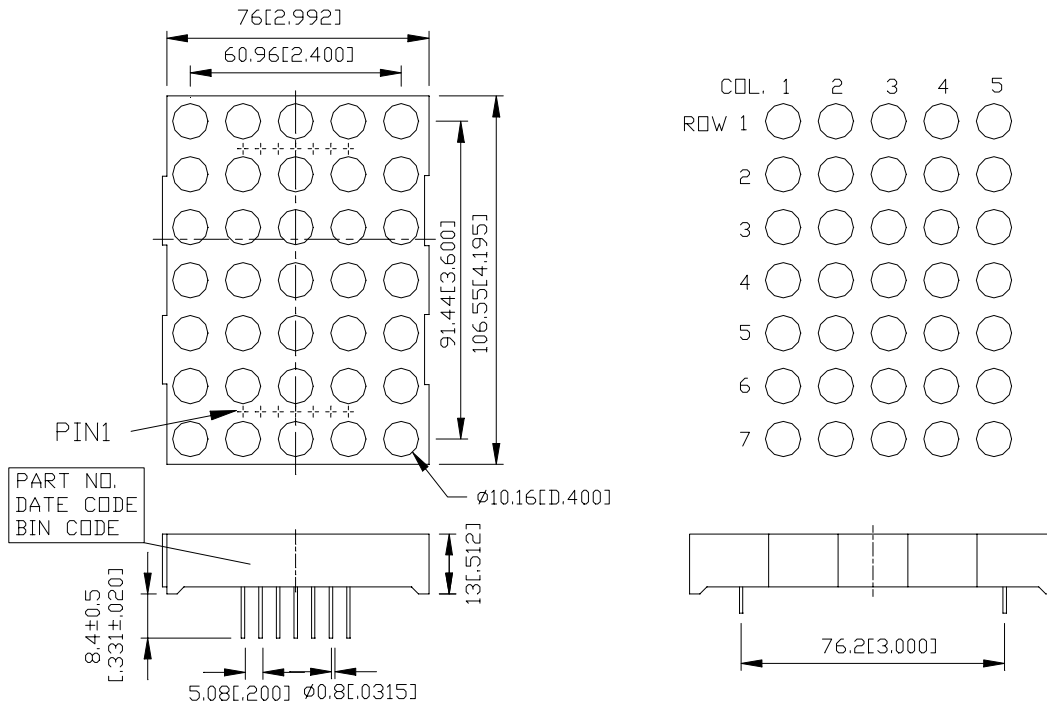
**DESCRIPTION**

The LTP-4157AC-02 is a 4.0 inch ( 101.6 mm) matrix height 5 x 7 dot matrix displays. This device utilizes AlGaAs red LED chips, which are made from AlGaAs on a non-transparent GaAs substrate, and has a red face and red dot.

**DEVICE**

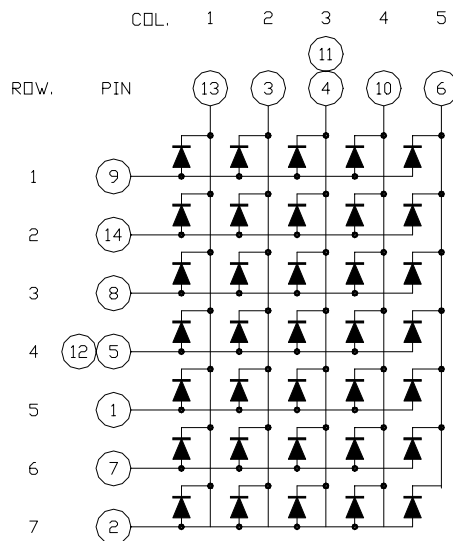
<b>PART NO.</b>	<b>DESCRIPTION</b>
AlGaAs RED	Cathode Column
LTP-4157AC-02	Anode Row

## PACKAGE DIMENSIONS



NOTES: All dimensions are in millimeters. Tolerances are  $\pm 0.25$ -mm (0.01“) unless otherwise noted.

## INTERNAL CIRCUIT DIAGRAM



**PIN CONNECTION**

<b>No.</b>	<b>CONNECTION</b>
1	ANODE ROW 5
2	ANODE ROW 7
3	CATHODE COLUMN 2
4	CATHODE COLUMN 3
5	ANODE ROW 4
6	CATHODE COLUMN 5
7	ANODE ROW 6
8	ANODE ROW 3
9	ANODE ROW 1
10	CATHODE COLUMN 4
11	CATHODE COLUMN 3
12	ANODE ROW 4
13	CATHODE COLUMN 1
14	ANODE ROW 2

**ABSOLUTE MAXIMUM RATING AT T<sub>A</sub>=25°C**

PARAMETER	MAXIMUM RATING	UNIT
Average Power Dissipation Per dot	64	mW
Peak Forward Current Per dot	110	mA
Average Forward Current Per dot	14	mA
Derating Linear From 25°C Per dot	0.19	mA/°C
Reverse Voltage Per dot	10	V
Operating Temperature Range	-35°C to +85°C	
Storage Temperature Range	-35°C to +85°C	
Solder Temperature 1/16 inch Below Seating Plane for 3 Seconds at 260°C		

**ELECTRICAL / OPTICAL CHARACTERISTICS AT T<sub>A</sub>=25°C**

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	I <sub>v</sub>	11600	20000		μcd	I <sub>F</sub> =80mA , 1/16Duty
Peak Emission Wavelength	λ <sub>p</sub>		660		nm	I <sub>F</sub> =20mA
Spectral Line Half-Width	Δλ		35		nm	I <sub>F</sub> =20mA
Dominant Wavelength	λ <sub>d</sub>		638		nm	I <sub>F</sub> =20mA
Forward Voltage Per dot	V <sub>F</sub>		3.6	4.8	V	I <sub>F</sub> =20mA
			4	5.4	V	I <sub>F</sub> =80mA
Reverse Current Per dot	I <sub>R</sub>			100	μA	V <sub>R</sub> =10V
Luminous Intensity Matching Ratio	I <sub>v-m</sub>			2:1		I <sub>F</sub> =10mA

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (commission internationale DE L'clairage) eye-response curve.

## TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

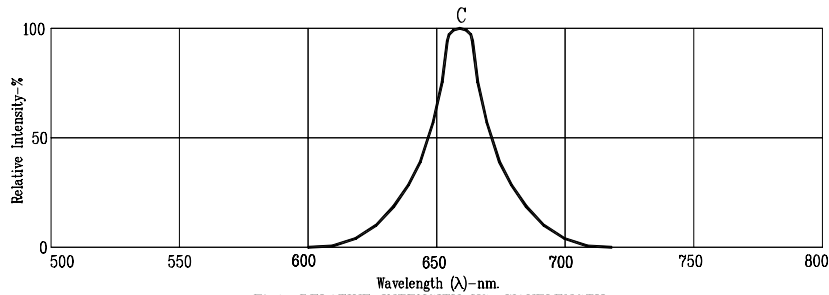


Fig1. RELATIVE INTENSITY VS. WAVELENGTH

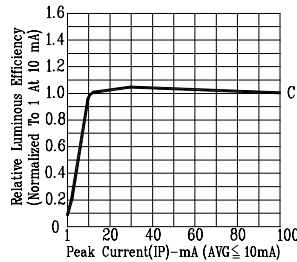


Fig2. RELATIVE LUMINOUS EFFICIENCY (LUMINOUS INTENSITY PER UNIT CURRENT) VS. PEAK CURRENT (REFRESH RATE 1KHz)

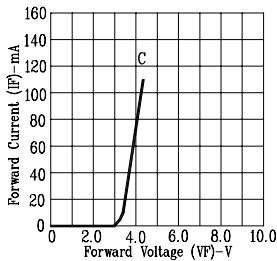


Fig3. FORWARD CURRENT VS. FORWARD VOLTAGE

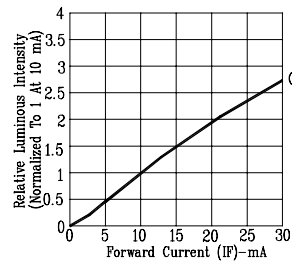


Fig4. RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT

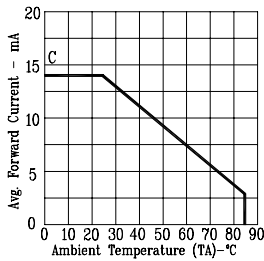


Fig5. MAX. AVERAGE FORWARD CURRENT VS. AMBIENT TEMPERATURE.

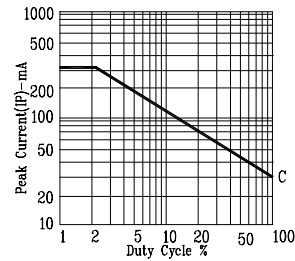


Fig6. MAX. PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE 1KHz)

NOTE : C=AlGaAs RED